

Cite this: *RSC Adv.*, 2018, 8, 26169

Received 23rd May 2018

Accepted 15th July 2018

DOI: 10.1039/c8ra04417a

rsc.li/rsc-advances

# Exfoliation, point defects and hydrogen storage properties of monolayer $\text{TiS}_3$ : an *ab initio* study

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The possibility of  $\text{H}_2$  molecule adsorption on the basal plane of monolayer  $\text{TiS}_3$  at various sites has been studied. Among the studied adsorption sites, few sites were found to be suitable for physisorption with binding energy up to 0.10 eV per  $\text{H}_2$ . To increase the activity of hydrogen sorption, the possibility of generating S-vacancies, by removing sulfur atoms from the basal plane of monolayer  $\text{TiS}_3$ , was investigated. Despite the fact that the structures containing vacancies were found to be stable enough, there was no increase in the activity towards hydrogen adsorption. The same effect was obtained with the use of common methods of increasing of the  $\text{H}_2$  adsorption energy: the decoration of the two-dimensional material with alkali metals (Li, Na). This might be caused by the negatively charged surfaces of single layer  $\text{TiS}_3$ , which hinder the increase in binding by alkali metals through a weak electrostatic interaction.

## 1. Introduction

Transition metal dichalcogenides (TMDC) with formula  $\text{MX}_2$  that refers to a metal atom (M) sandwiched between two layers of chalcogen atoms (X) form two-dimensional (2D) honeycomb structures. The remarkable properties of TMDCs lead to a wide range of applications, including in optoelectronics, transistors, energy storage, solar cells, and catalysts.<sup>1–5</sup> Currently, it is not possible to find an efficient environment for storing hydrogen under normal conditions.<sup>6–8</sup> The developed hydrogen storage system must have high values of gravimetric and volumetric capacities at room temperature and ambient pressure. Moreover, the US Department of Energy (DOE) has set the following targets for efficient hydrogen storage materials: (1) the gravimetric and volumetric capacities should be at least 7.5 wt% and  $70 \text{ g l}^{-1}$ , respectively, (2) the operating temperature range from  $-40^\circ\text{C}$  to  $60^\circ\text{C}$ , (3) safety and durability (1500 operation cycles).<sup>9</sup> In addition, the adsorption energy values should be in the range of  $-0.2$  to  $-0.7$  eV per  $\text{H}_2$ .<sup>10</sup> This range of adsorption energy values is intermediate between physical adsorption and chemisorption and is ideally suited for hydrogen storage under ambient pressure and temperature. Kubas interaction, as well as weak electrostatic interaction exhibit binding energy in this range.<sup>11,12</sup> To achieve these parameters, scientists have carried

out theoretical and experimental studies to many of materials capable for hydrogen storage. Early research was based on metal hydrides,<sup>13</sup> while other materials such as graphene,<sup>14,15</sup> fullerenes<sup>16,17</sup> and carbon nanotubes<sup>18</sup> are rapidly developing, since they have a high specific surface area, fast kinetics, and reversibility of the adsorption of hydrogen molecules. However,  $\text{H}_2$  molecules bind weakly to pure graphene, which is chemically too inert to act as a promising material for hydrogen storage.<sup>19,20</sup> To increase the chemical activity of graphene, attempts are made such as doping<sup>21</sup> and decorating.<sup>22–26</sup> Since graphene showed satisfactory characteristics, other graphene materials attracted the attention of researchers. Examples including silicene,<sup>27–29</sup> monolayer black phosphorus,<sup>30</sup> arsenene<sup>31</sup> and porous graphene.<sup>10,21,24,32</sup> The other potential materials are metal-organic compounds,<sup>33,34</sup> monolayers of  $\text{MoS}_2$ ,<sup>35</sup>  $\text{Cr}_2\text{C}$ <sup>36</sup> and transition metal hydrazides.<sup>37–39</sup> Among them, two dimensional (2D) materials are gaining attention due to their large surface area to volume ratio. Such 2D systems act as substrates onto which the metal atoms are to be dispersed to adsorb  $\text{H}_2$  molecules through different mechanisms. Alkali atoms tend to attract  $\text{H}_2$  molecules *via* electrostatic interaction, while transition metals adsorb  $\text{H}_2$  through the Kubas interaction.<sup>40–44</sup> Some examples are Sc-decorated porous graphene,<sup>24</sup> calcium-decorated graphene-based nanostructures,<sup>26</sup> Li-decorated  $\text{MoS}_2$ .<sup>35</sup> However, the search of materials that can meet these requirements is still an urgent task. For example, it was found that the binding energy per Li atom on graphene is weaker than Li cohesive energy, and it tend to clustering.<sup>14</sup> Thus, a two-dimensional material with a more chemically active surface is needed in order to bind the decorating metal and distribute it evenly along the surface. There are many other materials potentially capable of demonstrating this

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property,<sup>45,46</sup> such as graphane functionalized by polyolithiated species,<sup>47</sup> biphenylene carbon functionalized with alkali and alkaline earth metals,<sup>48</sup> Li-doped defective graphene with B substitution,<sup>49</sup> Li-decorated defective phosphorene<sup>50</sup> and Li decorated two-dimensional C<sub>2</sub>N.<sup>51</sup> Among them, the hydrogen storage properties of 2D crystals based on transition metal chalcogenides, which has been studied less intensively. The properties of monolayer TiS<sub>3</sub>, which was found to be stable using full phonon dispersion spectrums, are unexplored.<sup>52</sup> Bulk TiS<sub>3</sub> proved to be promising as a cathode material for lithium, sodium, and magnesium batteries.<sup>52–55</sup>

The creation of sulfur vacancies in transition metal sulphides is an effective way of increasing their catalytic activity, as shown, for example, in the work on MoS<sub>2</sub>.<sup>56</sup> This could make TiS<sub>3</sub> reactive towards hydrogen adsorption through the creation of more active sites. Experimental generation of sulfur vacancies in TiS<sub>3</sub> can be performed using methods that have proven to be successful in creating sulfur vacancies in other sulphides of transition metals, like etching,<sup>57,58</sup> argon plasma<sup>59</sup> and electrochemical desulfurization.<sup>60</sup>

In this study we have chosen lithium and sodium, since lithium is light element, which is important for gravimetric capacity, and is also a classic example for creating systems storing hydrogen. Sodium is a cheap analogue of lithium, just as it is now recognized in the field of electrochemical batteries.

In this work, we present a first-principles computational study of the monolayer TiS<sub>3</sub> as a potential candidate for an efficient hydrogen storage. To increase the chemical activity, the creation of single and double vacancies in the sulfur sublattice, decorating with Li and Na will be used.

## 2. Methods

In this study, we investigated the stability of single and double sulphur vacancies in monolayer TiS<sub>3</sub>. If not otherwise noted, we used a  $2 \times 3 \times 1$  supercell whose height was 20 Å. For single and double sulphur vacancies, the supercells correspond to  $x = 0.0833$  and  $0.1667$  in TiS<sub>3–x</sub>, respectively. The spin-polarized calculations of the electronic structural properties were carried out using Quantum ESPRESSO code.<sup>61</sup> The exchange-correlation energy functional was evaluated using the generalized gradient approximation (GGA) parameterized by Perdew, Burke, and Ernzerhof.<sup>62</sup> We employed the Kleinman–Bylander<sup>63</sup> form of norm-conserving ultrasoft Vanderbilt pseudopotentials.<sup>64</sup> A plane-wave cutoff of 530 eV was used, and a Monkhorst–Pack  $3 \times 3 \times 1$   $k$ -point grid was used to sample the Brillouin zone. The lattice parameters of TiS<sub>3</sub> were found to be  $a = 4.929$  Å,  $b = 3.392$  Å and  $c = 8.786$  Å, in a close agreement with the experimental values of  $a = 4.948$  Å,  $b = 3.379$  Å and  $c =$

8.748 Å (Table 1).<sup>65</sup> The geometry of the crystal cell was optimized with BFGS<sup>66</sup> algorithm. The van der Waals density functional (vdW-DF), a method based on the one proposed by Guillermo Roman-Perez and Jose M. Soler,<sup>67</sup> was used for geometry optimization and calculation of sorption energies of hydrogen molecules. We relaxed atomic positions and lateral dimensions of the  $(2 \times 3)$  TiS<sub>3</sub> layer with and without vacancy structures until all components of forces acting on each atom reach  $0.01 \text{ eV Å}^{-1}$  and the structures are stress-free. The convex hull graphs were plotted using data which were retrieved from the Materials Project database,<sup>68</sup> the Python Materials Genomic (pymatgen) package,<sup>69</sup> through the Materials API framework.<sup>70</sup>

The formation energy per vacancy of  $n$  sulfur vacancies is defined by:

$$E_f = \frac{1}{n} (E_{\text{Ti}_{12}\text{S}_{36-n}} + nE_S - E_{\text{Ti}_{12}\text{S}_{36}}) \quad (1)$$

where  $E_{\text{Ti}_{12}\text{S}_{36-n}}$ ,  $E_{\text{Ti}_{12}\text{S}_{36}}$  and  $E_S$  are the total energies of  $(2 \times 3)$  TiS<sub>3</sub> with and without  $n$  sulfur vacancies, and of an isolated sulfur atom, respectively.

To analyze the peculiarities of the adsorption of Li/Na atom on the monolayer TiS<sub>3</sub>, we calculated the binding energy using the following equation:

$$E_{\text{b,Li/Na}} = E_{\text{TiS}_3} + E_{\text{Li/Na}} - E_{\text{TiS}_3\text{-Li/Na}} \quad (2)$$

where  $E_{\text{TiS}_3\text{-Li/Na}}$  and  $E_{\text{TiS}_3}$  are the total energies of Li/Na-adsorbed TiS<sub>3</sub> and pure TiS<sub>3</sub>, respectively.  $E_{\text{Li/Na}}$  are the total energies of bulk bcc Li/Na. If  $E_b$  is positive, the adsorption reaction is exothermic (favorable), which indicates the Li/Na atoms tend to bind to the monolayer TiS<sub>3</sub>.

The adsorption energy of the  $n$ th hydrogen molecule,  $E_{\text{ads},n\text{H}_2}$ , is calculated using

$$E_{\text{ads},n\text{H}_2} = -E_{n\text{H}_2 \text{ on TiS}_3\text{-Li/Na/vac}}^{H_2} + E_{n-1\text{H}_2 \text{ on TiS}_3\text{-Li/Na/vac}}^{H_2} + E_{H_2} \quad (3)$$

where  $E_{n-1\text{H}_2 \text{ on TiS}_3\text{-Li/Na/vac}}^{H_2}$  is the energy of the system (pristine monolayer TiS<sub>3</sub>, TiS<sub>3</sub> covered with Li/Na or TiS<sub>3</sub> with  $S$  vacancies) with  $(n-1)\text{H}_2$  molecules adsorbed and  $E_{H_2}$  is the energy of a single hydrogen molecule.

The average adsorption energy per hydrogen molecule,  $\langle E_{\text{ads},H_2} \rangle$ , is calculated via

$$\langle E_{\text{ads},H_2} \rangle = \frac{1}{n} (-E_{n\text{H}_2 \text{ on TiS}_3\text{-Li/Na/vac}}^{H_2} + E_{\text{TiS}_3\text{-Li/Na/vac}} + nE_{H_2}) \quad (4)$$

where  $E_{H_2 \text{ on TiS}_3\text{-Li/Na/vac}}$  is the energy of the system (pristine monolayer TiS<sub>3</sub>, TiS<sub>3</sub> covered with Li/Na or TiS<sub>3</sub> with  $S$  vacancies) with adsorbed hydrogen molecules and  $nE_{H_2}$  is the energy of  $n$  hydrogen molecules.

## 3. Results and discussion

A full geometry optimization of both atomic coordinates and lattice parameters for the bulk and monolayer TiS<sub>3</sub> were first performed. The use of van der Waals density functional (vdW-DF) functional allow us to reach a very close agreement with the experimental value of parameter  $c$  (Table 1).<sup>65,67</sup> Fig. 1 shows the structure of TiS<sub>3</sub> (space group  $P2_1/m$ ). The structure contains

Table 1 Optimized and experimental lattice parameters (Å)

	Optimized	Experiment <sup>65</sup>
$a$	4.929	4.948
$b$	3.392	3.379
$c$	8.786	8.748



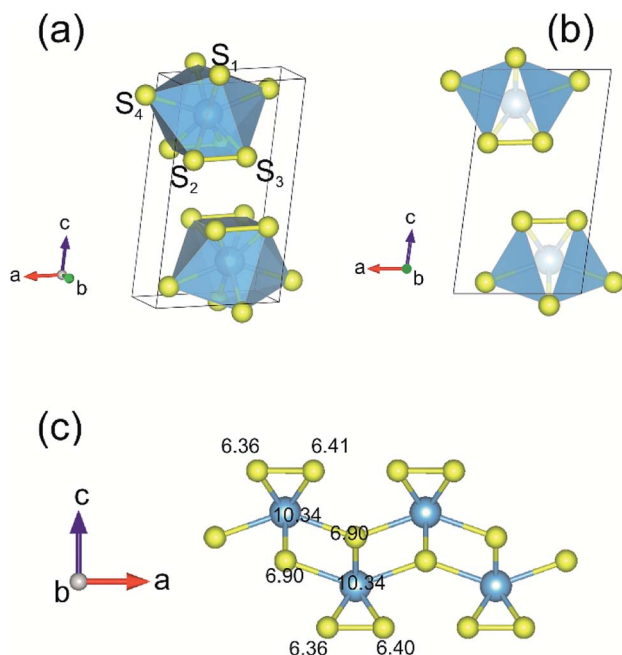


Fig. 1 (a) Structure of  $\text{TiS}_3$ . The blue and yellow balls represent the Ti and S atoms, respectively.  $\text{S}_1$  is sulfide ( $\text{S}^{2-}$ ), and  $\text{S}_2$  and  $\text{S}_3$  are disulfide ( $\text{S}_2^{2-}$ ). (b) Side view of bulk  $\text{TiS}_3$ . The calculated valence charges on the inner and outer S and Ti atoms for monolayer  $\text{TiS}_3$  are also shown (c).

a single-bonded disulfide ion ( $\text{S}_2^{2-}$ ), labeled in the figure as  $\text{S}_2$ – $\text{S}_3$ , and the third sulfur atom which is formally sulfide ( $\text{S}^{2-}$ ) ( $\text{S}_1$ ). The single layer of  $\text{TiS}_3$  differs from that of the most widely studied monolayer transition metal dichalcogenides ( $\text{TaS}_2$ ,  $\text{WS}_2$ ,  $\text{WSe}_2$ ,  $\text{TaSe}_2$ , *etc.*),<sup>71–75</sup> including  $\text{TiS}_2$ ,<sup>76</sup> where there are no dichalcogenide ions. These structural features of  $\text{TiS}_3$  can affect the sorption of hydrogen by the surface in its monolayer state, the interaction of hydrogen molecules with the surface and the appearance of the configurations of adsorbed hydrogen molecules.

Charge density analysis is an efficient tool to discuss the characters of the interatomic interactions and bonding. Bader charge analysis shows a significant amount of charge is transferred from Ti to the S atoms. While the S atoms at the surface share 0.8 electrons donated by the underlying Ti atom, 0.9 electron transfer occurs from Ti to S atom in the middle, in agreement with the work of Iyikanat *et al.*<sup>77</sup> It is also worth mentioning that the negatively charged surface of monolayer  $\text{TiS}_3$  may find interesting applications such as nanoscale lubricants and charged coatings, and this feature can certainly affect the sorption of hydrogen by systems containing the alkali cations which adsorb  $\text{H}_2$  by the electrostatic interaction route.

For the study of structural changes taking place when peeling off a single layer  $\text{TiS}_3$  and to estimate the peeling energy, we constructed a set of cells based on the structure of  $\text{TiS}_3$  with interlayer distance being set by hand. The atoms and structure were then allowed to relax to reach an equilibrium positions with  $c$  fixed, so as to obtain a binding energy curve as a function of the  $c$ -axis length as shown in Fig. 2c. As expected, the structural changes of  $\text{TiS}_3$  when exfoliating the monolayer  $\text{TiS}_3$  are

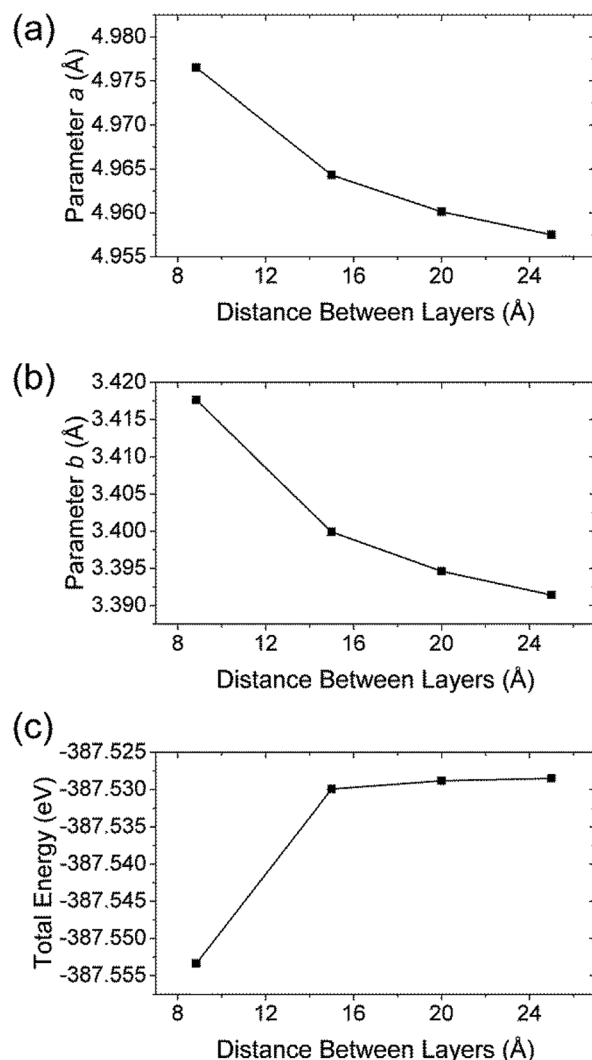


Fig. 2 The dependence of (a) parameter  $a$ , (b) parameter  $b$  and (c) total energy vs. spacing between layers in  $\text{TiS}_3$ .

small (Fig. 2a,b). If to calculate in percent, then the change in the parameter  $a$  is  $-0.4\%$ , while the parameter  $b$  is  $-0.8\%$ . Thus, although the changes in parameters  $a$  and  $b$  are negligible, the contraction of the structure along the  $b$ -axis is twice as large as along the direction of the  $a$ -axis.

The peeling energy per area  $S$  of monolayer  $\text{TiS}_3$  was calculated using:

$$E_{\text{XF}} = \frac{1}{S} (E_{\text{TiS}_3}^{\text{bulk}} - E_{\text{TiS}_3}^{\infty}) \quad (5)$$

where  $E_{\text{TiS}_3}^{\text{bulk}}$  and  $E_{\text{TiS}_3}^{\infty}$  are the total energy of bulk  $\text{TiS}_3$  and  $\text{TiS}_3$  with infinite distance between layers, respectively. In the latter case the total energy of a cell with a distance between layers sufficient to neglect the interaction between them (25 Å) was used. The value of the peeling energy calculated by us is 19.901 eV, which corresponds to the values of energies for most systems obtained by Björkman *et al.* (around 20 meV Å<sup>-2</sup>).<sup>78</sup> Such universality explains the successful exfoliation of a wide class of layered materials to produce two-dimensional systems.



Unfortunately, in Björkman's work, values for trichalcogenides were not calculated. The value of the peeling energy for  $\text{TiS}_2$  calculated in his work is 24.552 eV and gradually decreases with increasing atomic weight of the chalcogenide atom (22.952 eV for  $\text{TiSe}_2$  and 22.016 eV for  $\text{TiTe}_2$ ).<sup>78</sup> Nevertheless, we have a somewhat smaller value for  $\text{TiS}_3$  here, which indicates a greater ease of exfoliation.

The experimental work of Barawi *et al.* of the hydrogen storage of monolayer  $\text{TiS}_3$  showed that it is hard to absorb hydrogen for hydrogen pressures up to 80 bar and reaction temperatures up to 300 °C.<sup>79</sup> Thus, more detailed studies of the process of hydrogen adsorption by pure two-dimensional  $\text{TiS}_3$  sheets were carried out by computer simulation. To increase the chemical activity of titanium, we also investigated the effect of creation of single and double vacancies in the sulfur sublattice on the hydrogen storage properties of monolayer  $\text{TiS}_3$ . A  $2 \times 3 \times 1$  supercell was used as the base simulation cell. To create a single vacancy in the sulfur sublattice, there are only two non-equivalent positions ( $S_1$  and  $S_2$  as indicated in Fig. 1a). In the case of double vacancies, the situation is different. It is necessary to consider all possible variants of the relative locations of the two sulfur vacancies. For this purpose, the Python Materials Genomic (pymatgen) package<sup>80</sup> was used to generate a set of 70 supercells. These supercells were used in Quantum ESPRESSO, followed by geometry optimization. The obtained total energy values for the supercells containing single and double vacancies were used to calculate the energy above hull ( $E^{\text{hull}}$ ) parameter (see Methods section). This parameter indicates the thermodynamic stability of the material, and equals the thermodynamic decomposition energy of the compound.<sup>80–83</sup> The zero  $E^{\text{hull}}$  indicates stability, while greater than 100 meV per atom indicates driving force to form other phases, which may be reflected as difficulty in synthesizing a compound, or as decomposition.<sup>83</sup> According to the work of Sun *et al.*<sup>83</sup> the energy difference of 100 meV/atom between thermodynamically metastable compounds and thermodynamically stable phases can be overcome by entropy  $\Delta S$  of  $10 \text{ J mol}^{-1} \text{ K}^{-1}$  at  $\sim 1000 \text{ K}$ ,  $\sim 10 \text{ GPa}$  pressure or  $\sim 10 \text{ nm}$  particle size. Thus, the energy above hull ( $E^{\text{hull}}$ ) parameter indicates the thermodynamic stability of  $\text{TiS}_3$  containing sulfur vacancies and its tendency to decompose into more stable phases.

Fig. 3 displays the energy above the convex ground state energy hull ( $E^{\text{hull}}$ ) of  $\text{TiS}_{3-x}$  ( $x = 0, 0.0833$  and  $0.1667$ ) with respect to the Ti–S binary phase diagram. The decomposition products and  $E^{\text{hull}}$  values for each of the compositions are listed in Table 2, and calculated for compounds, suggested as stable by Materials Project resources.<sup>68</sup> From Table 2, it follows that the products of decomposition of monolayer  $\text{TiS}_3$  containing sulfur vacancies can be  $\text{TiS}_3$  and  $\text{TiS}_2$ . However, the  $E^{\text{hull}}$  values are small enough so that it does not happen ( $E^{\text{hull}} \sim 100 \text{ meV}$  per atom). In addition, from the  $E^{\text{hull}}$  graph, the increase in the concentration of vacancies gradually increases stability ( $E^{\text{hull}}$  values approach 0.100 eV per atom). The  $E^{\text{hull}}$  value for monolayer  $\text{TiS}_3$  is not zero (Fig. 3, Table 2), since the energy is required to exfoliate the monolayer  $\text{TiS}_3$  from bulk  $\text{TiS}_3$ . For supercell containing one sulfur vacancy ( $x = 0.0833$  in  $\text{TiS}_{3-x}$ , Fig. 3), there is a significant difference in the stability of the

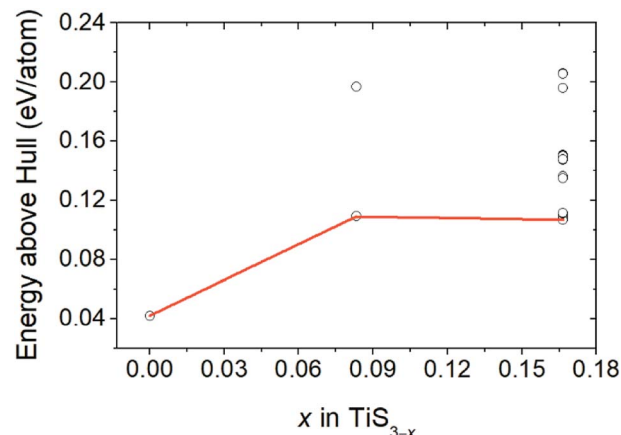


Fig. 3 Energy above hull ( $E^{\text{hull}}$ ) values for  $\text{TiS}_3$  containing sulfur vacancies ( $\text{TiS}_{3-x}$  ( $x = 0, 0.0833$  and  $0.1667$ )).

Table 2 The  $E^{\text{hull}}$  values (in eV per atom) and the corresponding decomposition products are listed as a function of sulfur vacancies content in monolayer  $\text{TiS}_3$ , as obtained from the Materials Project database<sup>68</sup>

Composition	$E^{\text{hull}}$	Decomposition products
Monolayer $\text{TiS}_3$	0.042	$\text{TiS}_3$
Monolayer $\text{TiS}_{2.917}$	0.109	$\text{TiS}_3 + \text{TiS}_2$
Monolayer $\text{TiS}_{2.833}$	0.107	$\text{TiS}_3 + \text{TiS}_2$

sulfur vacancy located at positions  $S_1$  and  $S_2$ . This is because the extraction of sulfur from the surface of the monolayer  $\text{TiS}_3$  ( $S_2$ ) is less energy-intensive than from its central part ( $S_1$ ). The optimized most stable structures of  $\text{TiS}_3$  containing sulfur vacancies are shown in Fig. 4. When the single S vacancy is created, the lattice vectors of  $2 \times 3 \times 1$  supercell change to  $a = 10.379 \text{ Å}$  and  $b = 10.699 \text{ Å}$ . Thus, the presence of the S vacancy leads to a minute expansion of the lattice vectors of  $\text{TiS}_3$ . Our calculated results show that the formation energy of S vacancy is 3.87 eV, in agreement with Iyikanat *et al.* work.<sup>77</sup> In the case of the content of two vacancies in the supercell, there is no clustering of vacancies (Fig. 4b and d). This is in contrast with a computer simulation results for monolayer  $\text{MoS}_2$ ,<sup>56,60</sup> where S vacancies were found to form in clusters. Tsai *et al.*<sup>60</sup> suggested that this is because it is more exergonic to form a vacancy close to an existing one. These results were confirmed by experiments on electrochemical desulfurization of the  $\text{MoS}_2$  basal plane.<sup>60</sup> However, there are other experiments where S-vacancies are evenly spread out in  $\text{MoS}_2$  nanosheet, such as Ar-plasma treatment.<sup>84</sup> In the case of double sulfur vacancies in  $\text{TiS}_3$ , the formation energies of possible vacancies of S, Ti, TiS, and double S were calculated by Iyikanat *et al.* via total energy optimization calculations.<sup>77</sup> In that work, Iyikanat *et al.* found that the formation of single S vacancy was the most likely one among the considered vacancy types. Our results are in agreement with Iyikanat *et al.* work: S vacancies are well separated from each other, on the opposite sides of the  $\text{TiS}_3$  nanosheet (Fig. 4b and d). Compared to the defect-free structure, when





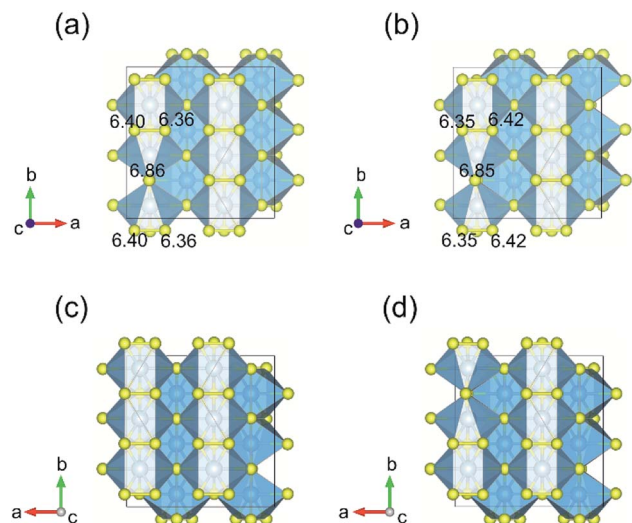


Fig. 4 Top (a and b) and bottom (c and d) views of the geometry optimized structures of  $2 \times 3 \times 1$  supercell, containing one and two sulfur vacancies, respectively. Numbers denote the valence charges on S atoms in the vicinity of the S vacancy.

both one and two S atoms are removed, the changes in lattice parameters are remarkable (Table 3). The formation energy of two S vacancies in the  $2 \times 3 \times 1$  supercell is 2.70 eV per vacancy. Using eqn (2), the formation energies of one and two vacancies in the  $\text{TiS}_3$   $2 \times 3 \times 1$  supercell were calculated, which corresponds to the compositions of  $\text{TiS}_{3-x}$  ( $x = 0.0833$  and  $0.1667$ ), respectively (Fig. 5). The dependence of the formation energy on the concentration of vacancies is in contrast to that of  $\text{MoS}_2$ , where the variation of formation energy is not large.<sup>56</sup>

Bader charge analysis shows that the creation of one S vacancy in the  $\text{TiS}_3$   $2 \times 3 \times 1$  supercell leads to accumulation of electrons on S atom (6.86 e), which shifted to the greatest distance in the process of structure relaxation (Fig. 4a), in agreement with work of Iyikanat *et al.*<sup>77</sup> For two S vacancies per cell, the situation is identical (Fig. 4b).

When considering the tendency of vacancies to form in an oriented distribution, it should be mentioned that monolayer  $\text{TiS}_3$  has strong in-plane structural anisotropy. Briefly, the structure of monolayer  $\text{TiS}_3$  can be represented as a set of 1D chains made of an  $\text{TiS}_6$  polyhedron extending along the  $b$ -direction (Fig. 1a). These chains are combined into a layer through a weak coupling, and thus anisotropy effects are anticipated. This property is also a characteristic to others transition metal trichalcogenides (TMTCs), with  $\text{MX}_3$  formula and in

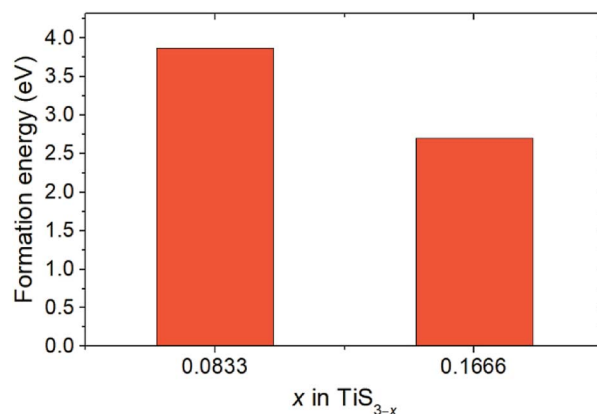


Fig. 5 Sulfur vacancy formation energies for  $x = 0.0833$  and  $0.1667$  in  $\text{TiS}_{3-x}$ .

contrast to isotropic transition metal dichalcogenides (TMDCs) with  $\text{MX}_2$  formula where M stands for transition or post-transition metal atoms and X is the chalcogen group (S, Se, and Te).<sup>1,85</sup> This structural anisotropy causes anisotropy of the properties, such as anisotropic electronic mobility, particularly high electronic mobility along the chain direction.<sup>86</sup> Due to the structural in-plane anisotropy of TMTCs, the flakes cleave easily along the  $b$ -axis, resulting in needle-like few-layered flakes with a large geometric aspect ratio ( $a/b < 1$ ).<sup>85</sup> Along with a needle-shaped form, TMTCs also appear in the form of nanobelts.<sup>87,88</sup> Thus, for mono- and few-layered  $\text{TiS}_3$ , the hydrogen can be stored both by the edge and the basal plane. In this work, we investigate the ability of monolayer  $\text{TiS}_3$  to store hydrogen by the basal plane.

The process of sorption of cations on monolayer  $\text{TiS}_3$  was investigated earlier, see, for example, lithium and sodium sorption on  $\text{TiS}_3$  by Wu *et al.*<sup>52</sup> For the consideration of lithium and sodium sorption, these authors suggested using H,  $T_1$  and  $T_2$  sites (Fig. 6a), which we also used in our work. As can be seen in Fig. 6a, there are three different high symmetry sites for monolayer  $\text{TiS}_3$  *i.e.* H,  $T_1$  and  $T_2$  sites. These positions were used to find the most stable adsorption site for Li, Na atoms and hydrogen molecules. The most stable configurations of Li and Na adsorbed on monolayer  $\text{TiS}_3$  are shown in Fig. 6b and c, respectively. According to our calculations, sorption of Li and Na in position H is the most favorable, in agreement with results of Wu *et al.*<sup>52</sup> Li and Na adsorption stretches the  $\text{TiS}_3$  sheet (parameter  $a$  increased by 5%, parameter  $b$  – by 3% for Li; for Na – 4 and 3%, respectively). To estimate the influence of adsorption on the Ti–S bond length, let us consider the structure of  $\text{TiS}_3$  sheet as a set of 1D chains made of  $\text{TiS}_6$  trigonal prisms formed by  $\text{Ti–S}_1\text{–S}_2\text{–S}_3$  atoms (Fig. 1a). These chains are connected to each other through longer  $\text{Ti–S}_4$  bonds (Fig. 1a). The  $\text{Ti–S}_4$  equilibrium bond length of 2.658 Å for the pristine  $\text{TiS}_3$  increases to 2.763 and 2.740 Å for Li and Na covered monolayer  $\text{TiS}_3$ , respectively (Table 4). If to visualize the crystal structure of Li covered monolayer  $\text{TiS}_3$  by VESTA with maximum Ti–S bond length recommended by this software,<sup>89</sup> it can be seen that the bonds between these chains disappear (Fig. 6d). This may indicate that the adsorption of sodium and especially

Table 3 Calculated lattice parameters, formation energies and binding energies of  $2 \times 3 \times 1$  supercell of monolayer  $\text{TiS}_3$ , its few defected forms and Li and Na decorated  $\text{TiS}_3$

	$a/b$ (Å)	$E_f$ (eV)	$E_b$ (eV)
Pristine $\text{TiS}_3$	9.858/10.176	—	—
One S vacancy	10.379/10.699	3.87	—
Two S vacancies	10.128/10.695	2.70	—
Li decorated $\text{TiS}_3$	10.352/10.453	—	1.12
Na decorated $\text{TiS}_3$	10.275/10.529	—	0.73



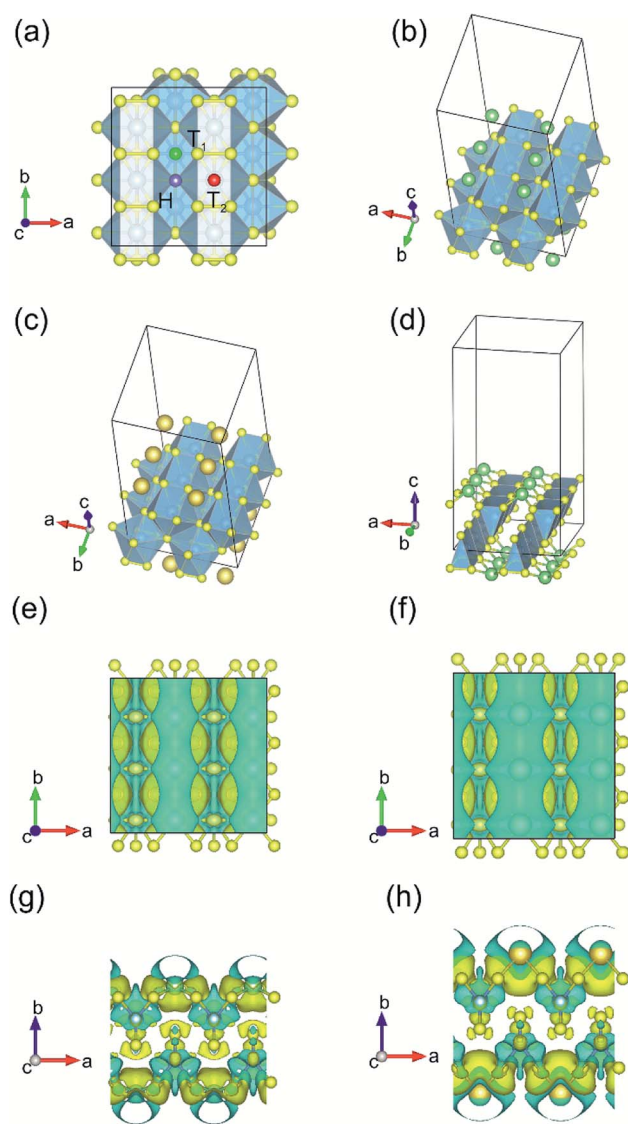


Fig. 6 (a) Adsorption sites on a  $2 \times 3 \times 1$  single layer  $\text{TiS}_3$  nanosheet: purple, green and red spheres denote H,  $T_1$  and  $T_2$  sites, respectively. (b and c) The most stable configurations of Li and Na adsorbed on monolayer  $\text{TiS}_3$ , respectively. The blue, yellow, green and gold balls represent the Ti, S, Li and Na atoms, respectively. (d) The crystal structure of Li covered monolayer  $\text{TiS}_3$  with maximum Ti–S bond length recommended by VESTA.<sup>49</sup> Isosurface of the difference charge density for the most stable configuration of Li (e and g) and Na (f and h) adsorbed on the monolayer  $\text{TiS}_3$ . Yellow regions indicate charge accumulation while cyan ones denote charge depletion. The isosurface level is set to  $0.005e \text{ \AA}^{-3}$ .

lithium can be used to split the monolayer of  $\text{TiS}_3$  into chains or substantially reduce the width of the nanobelts and needles. It can be seen that the increase of the Mg content absorbed by bulk  $\text{TiS}_3$  leads to break of the S–S bonds in the disulfide ion and conversion of similar effect was found in our recent work<sup>55</sup> when it was found the  $\text{TiS}_3$  layers into ribbons. It should be noted that the creation of single vacancy induces the same separation effect as Li/Na adsorption (parameter  $a$  increases to  $10.379 \text{ \AA}$ , see Table 3), however, for the case of two vacancies per the  $2 \times 3 \times 1$  supercell, this effect disappears quickly.

Table 4 Ti–S equilibrium bond length  $d_{\text{Ti-S}}$  ( $\text{\AA}$ ) for pristine and Li/Na absorbed monolayer  $\text{TiS}_3$

	$d_{\text{Ti-S}_1}$ ( $\text{\AA}$ )	$d_{\text{Ti-S}_2}$ ( $\text{\AA}$ )	$d_{\text{Ti-S}_4}$ ( $\text{\AA}$ )
Pristine $\text{TiS}_3$	2.485	2.521	2.658
Li decorated $\text{TiS}_3$	2.481	2.603	2.763
Na decorated $\text{TiS}_3$	2.491	2.592	2.740

Bader charge analysis shows the filling of surface S atoms with electrons (from 6.36–6.41 to up to 6.84 valence charge) donated by the Li cation (2.12 valence charge). The charge on the inner S atoms is unchanged (6.90 electrons). The described situation is in agreement with the difference in charge density, see Fig. 6e and g. There is a net loss of electronic charge right above the Li, whereas there is a net gain of electronic charge in the intermediate region between Li and four adjacent sulfur atoms, indicating a significant charge transfer from the adsorbed Li to its nearest neighbor S atoms (around 0.88 electrons). The highly charged Li atoms thus have a strong repulsion among each other, thereby again suggesting that they prefer a dispersed configuration rather than an aggregated one. In the meantime, this charge transfer polarizes the system, leading to the setting up of an electric field in the region between the Li atom and  $\text{TiS}_3$ , which is important for the  $\text{H}_2$  storage through electrostatic interaction. Somewhat smaller in magnitude (0.71 electrons), but the same in its manner, the donation of electrons is observed in the case of Na adsorbed on monolayer  $\text{TiS}_3$ , in agreement with the difference in charge density (Fig. 6f and h). These results suggest that the interaction between the adsorbed Li/Na atom and its nearest neighbor sulfur atoms is predominantly ionic, and the valence electrons of the adsorbed Li/Na atoms are mainly transferred to the neighbor sulfur atoms.

For hydrogen adsorption on these systems, we first analyzed the most stable structure of a single  $\text{H}_2$  molecule adsorbed on the surface. Three different high symmetry sites for monolayer  $\text{TiS}_3$  (H,  $T_1$  and  $T_2$ ) sites (Fig. 6a) were used for  $\text{H}_2$  molecule placement. H point is above the inner S atom,  $T_1$  is above the midpoint between outer S atoms,  $T_2$  is above the Ti atom. The center of mass of the hydrogen molecule was placed at a distance of  $2 \text{ \AA}$  from the surface according to recommendation of Putungan *et al.*,<sup>35</sup> in order for  $\text{H}_2$  molecules not to be too close or far away from the substrate. All these are combined with the several approach orientations of  $\text{H}_2$ . The hydrogen molecule was placed both horizontally and vertically. After the placement, all the atoms in the supercell were allowed to relax. Results of the investigation of  $\text{H}_2$  molecules adsorption on these sites for each of the systems studied are shown in Fig. 7 and 8, and Table 5.

In the case of  $\text{H}_2$  molecule adsorbed on monolayer  $\text{TiS}_3$  without vacancies, containing one and two S vacancies per  $2 \times 3 \times 1$  supercell, Bader charge analysis shows that  $\text{H}_2$  molecule does not loose nor gain any electrons. As follows from the difference in charge density (Fig. 7), the adsorption of the hydrogen molecule does not lead to a significant redistribution of the electrons in the systems under this study. If it is assumed that the hydrogen adsorption mechanism will be electrostatic,



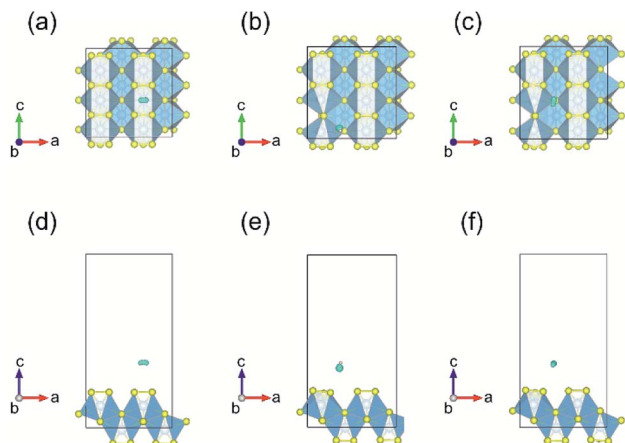


Fig. 7 Lowest energy adsorption configurations and corresponding charge density difference for hydrogen on the most stable site for  $2 \times 3 \times 1$  supercell of monolayer  $\text{TiS}_3$  without S vacancies (a and d), containing one (b and e) and two (c and f) sulfur vacancies. The iso-surface level is set to  $0.002e \text{ \AA}^{-3}$ .

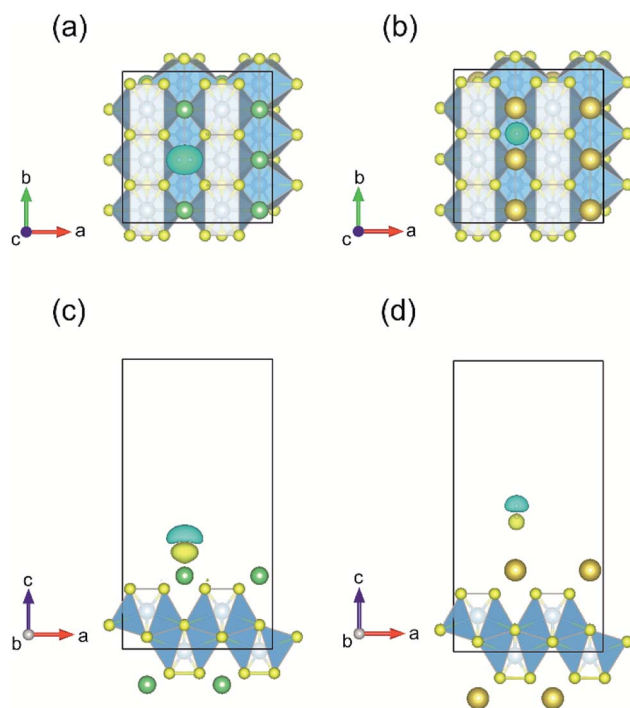


Fig. 8 Top and side views of the lowest energy adsorption configurations and corresponding charge density difference for  $\text{H}_2$  molecule on the monolayer  $\text{TiS}_3$  covered with Li (a and c) and Na (b and d). The isosurface level is set to  $0.002e \text{ \AA}^{-3}$ .

this can lead to low values of the adsorption energy. However, in this case many factors can participate in the process, and electrostatic one is only one of them.

In the case of  $\text{Li/TiS}_3$  system, the  $\text{H}_2$  gain very small charge (0.02 electrons), while the Li charge slightly increase (0.01 electrons). As for sodium adsorbed on  $\text{TiS}_3$  sheet, the  $\text{H}_2$  charge increase by 0.20 e, while the charge of the two closest Na cations decrease (8.19 electrons).

Table 5 Adsorption energies ( $E_{\text{ads}}$ ) (eV) of single  $\text{H}_2$  molecule adsorbed on monolayer  $\text{TiS}_3$ , its few defected forms and Li and Na decorated  $\text{TiS}_3$  (eV) at the H,  $T_1$  and  $T_2$  sites, respectively<sup>a</sup>

	Site		
	H	$T_1$	$T_2$
Pristine $\text{TiS}_3$	0.09 <sub>h</sub> , 0.09 <sub>v</sub>	0.08 <sub>h</sub> , 0.08 <sub>v</sub>	0.10 <sub>h</sub> , 0.09 <sub>v</sub>
One S vacancy	0.08 <sub>h</sub> , 0.08 <sub>v</sub>	0.07 <sub>h</sub> , 0.07 <sub>v</sub>	0.08 <sub>h</sub> , 0.07 <sub>v</sub>
Two S vacancies	0.10 <sub>h</sub> , 0.09 <sub>v</sub>	0.08 <sub>h</sub> , 0.08 <sub>v</sub>	0.09 <sub>h</sub> , 0.08 <sub>v</sub>
Li decorated $\text{TiS}_3$	0.13 <sub>h</sub> , 0.08 <sub>v</sub>	0.10 <sub>h</sub> , 0.09 <sub>v</sub>	0.09 <sub>h</sub> , 0.10 <sub>v</sub>
Na decorated $\text{TiS}_3$	0.09 <sub>h</sub> , 0.11 <sub>v</sub>	0.11 <sub>h</sub> , 0.11 <sub>v</sub>	0.10 <sub>h</sub> , 0.08 <sub>v</sub>

<sup>a</sup> The subscripts "h" and "v" in the bottom right corner indicate the two different initial orientations of the  $\text{H}_2$  molecule – parallel and perpendicular to the surface of monolayer  $\text{TiS}_3$ , respectively.

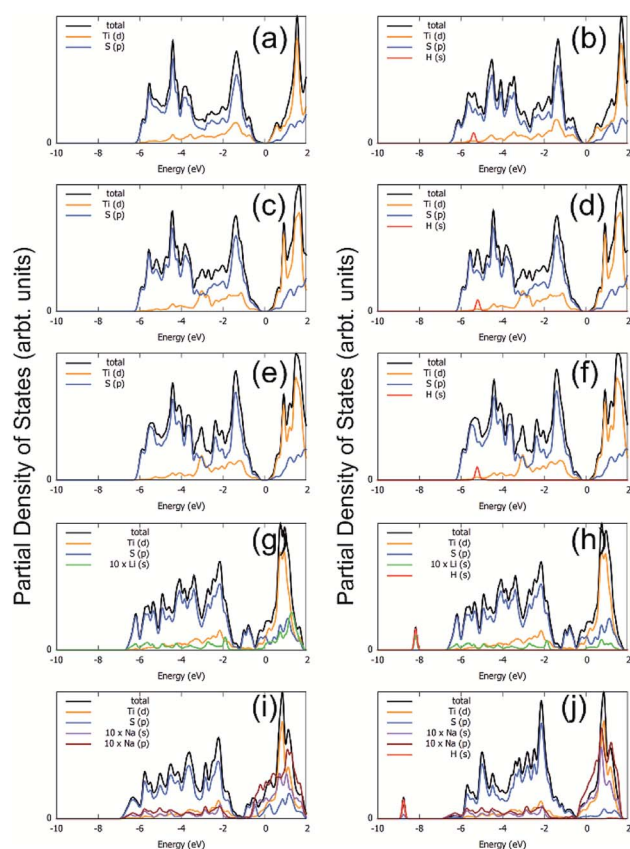
The total and partial density of states (PDOS) for all of the systems under study are shown in Fig. 9. As can be seen from the figures, removing one and two S atoms from the surface of  $\text{TiS}_3$  does not make any notable effect on the electronic structure of  $\text{TiS}_3$ , in agreement with work of Iyikanat *et al.*<sup>77</sup> (Fig. 9c and e). The monolayer  $\text{TiS}_3$  conserves its semiconductor character. Because of the reconstruction of the S atom and its binding with 2 Ti atoms, there are no unsaturated bonds.

Unlike the S vacancy, the Li/Na adsorption has a major effect on the electronic structure of  $\text{TiS}_3$ ; it loses its semiconductor character and becomes metallic. As shown in Fig. 9g and i, because of injection of electrons from Li/Na cations, the n-type doping is realized. Both p orbitals of S and d orbitals of Ti adsorb excess electrons, but Ti absorbs more.

When considering systems with adsorbed hydrogen, there is no charge transfer from  $\text{H}_2$  to Li/Na and  $\text{TiS}_3$  sheet. This fact eliminates the mechanism of electrostatic interaction from our consideration. The electric field induced around the positive charged Li/Na atoms does not polarize the  $\text{H}_2$  molecules. We believe that this field is hindered by the electrostatic field from the negatively charged monolayer  $\text{TiS}_3$ , the charge which is intrinsic to the monolayer  $\text{TiS}_3$ , as was shown by Iyikanat *et al.*<sup>77</sup> and was confirmed in our work (Fig. 1c). The initial  $\text{H}_2$  adsorption in this case is mostly mediated by the dipole interaction between Li/Na ion and  $\text{H}_2$  (induced) dipole moment. It is clear that the H atoms are polarized by the positively charge Li/Na atom. It is worth pointing out here, that  $\text{H}_2$  has zero dipole moment, but has a large quadrupole moment and high polarizability. Thus, these studies clearly indicate that the interaction between  $\text{H}_2$  and the Li/Na center to be dipole-quadrupole and dipole-induced dipole electrostatic in nature. A similar situation can occur in the case of pristine  $\text{TiS}_3$  and  $\text{TiS}_3$ , containing S vacancies: negatively charged surface could polarize the  $\text{H}_2$  molecule. In confirmation, it should be noted here that the largest polarization (difference of charge on H atoms 0.07 electrons) is realized in the case of pristine  $\text{TiS}_3$  sheet, indicating its substantial polarizing ability compared to other systems under the study. Although this mechanism is interesting in its origin, it may be not so effective like conventional alkali/transition metal systems. However, this mechanism requires further investigations. There is no stretching of the H–H bond, indicating the absence of  $\text{H}_2$  dissociation, which



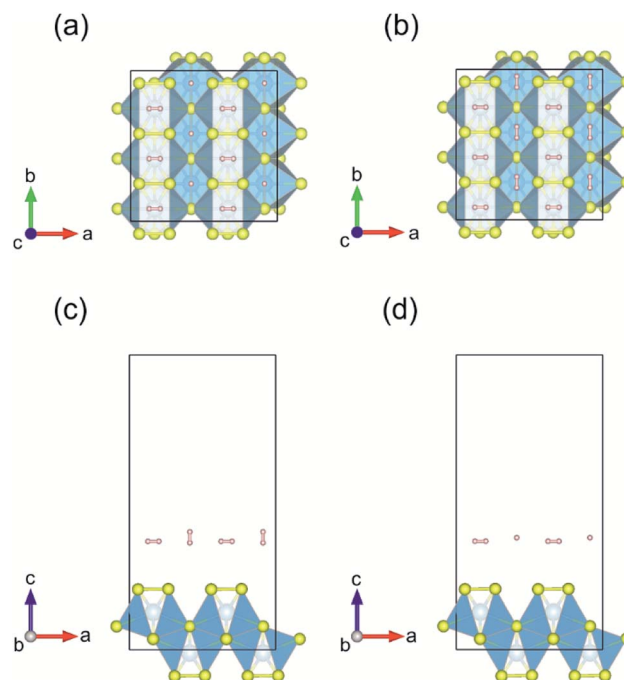




**Fig. 9** Total and partial density of states for  $\text{TiS}_3$  sheet bonded with alkali metal adatoms and single  $\text{H}_2$  molecule adsorbed on it (a)  $\text{TiS}_3$ , (b)  $\text{TiS}_3/\text{H}_2$  system, (c) one S vacancy, (d) one S vacancy/ $\text{H}_2$ , (e) two S vacancies, (f) two S vacancies/ $\text{H}_2$ , (g)  $\text{Li}/\text{TiS}_3$ , (h)  $\text{Li}/\text{TiS}_3/\text{H}_2$ , (i)  $\text{Na}/\text{TiS}_3$  and (j)  $\text{Na}/\text{TiS}_3/\text{H}_2$  system. Energies are given relative to the Fermi energy.

was found, for example, in the  $\text{Li}/\text{MoS}_2$  system by Putungan *et al.*<sup>35</sup> The PDOS for  $\text{Li}/\text{Na}$  adsorbed system (Fig. 9h and j) shows the overlap or hybridization of density states between H-s orbital and  $\text{Li}/\text{Na}$ -s orbitals appears at about  $-8$  eV ( $\text{Li}$ ) and  $-9$  eV ( $\text{Na}$ ), which increases the  $E_{\text{ads}}$ . Thus, besides the electrostatic interaction, electronic hybridization also plays roles in the adsorption process. Therefore, our analysis shows that the both, the hybridization of the  $\text{Li}/\text{Na}$ -s orbital with the H-s orbital and the polarization of the  $\text{H}_2$  molecules, contribute to the  $\text{H}_2$  adsorption.

Following the results for single  $\text{H}_2$  adsorption, a set of models was created for the first layer of hydrogen molecules adsorbed on  $\text{Li}/\text{Na}/\text{vac}-\text{TiS}_3$  system and compared them by total energy calculations. A similar approach was used by the Yadav *et al.*<sup>36</sup> The  $\text{H}_2$  molecules' positions were constrained (distance from  $\text{Li}/\text{Na}/\text{S}$  atom or S vacancy was  $2.0$  Å), in order for  $\text{H}_2$  molecules not to be too close or far away from the substrate, according to recommendation of Putungan *et al.*<sup>35</sup> Furthermore, to ensure that there are no overlapping spatial coordinates, a distance of  $2.0$  Å was imposed between two hydrogen atoms belonging to nearest neighbor  $\text{H}_2$  molecules. Fig. 10 shows the first layer of  $\text{H}_2$ -molecule adsorbed on pristine monolayer  $\text{TiS}_3$  for two models with the lowest value of total energy: Model-1

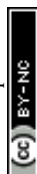


**Fig. 10** (a and b) Top and (c and d) side views of the first layer of  $\text{H}_2$ -molecule adsorbed on pristine monolayer  $\text{TiS}_3$  for Model-1 and Model-2, respectively.

(Fig. 10a and c) and Model-2 (Fig. 10b and d). The difference in the values of the total energy between these models is only  $0.013$  eV per atom, which indicate that at operating temperatures of the hydrogen storage device both models coexist. In fact, a mixture of these two models will take place, in which hydrogen molecule oriented along the  $c$  axis (Fig. 10a and c) will alternately orient along the  $c$  and  $b$  axes, in random fashion. The average values of the hydrogen adsorption energy  $\langle E_{\text{ads},\text{H}_2} \rangle$  for the first layer for all the cases considered by us calculated using eqn (4) are presented in Table 6. It can be seen that in general, adsorption does not satisfy the minimum value of  $0.2$  eV, recommended by DOE.<sup>9,10</sup> The hydrogen adsorption energy of the second layer for pristine monolayer  $\text{TiS}_3$  does not exceed  $0.01$  eV. Such a negative trend for pristine monolayer  $\text{TiS}_3$  has experimental confirmation in the work of Barawi *et al.*<sup>79</sup> For other cases considered by us ( $\text{Li}/\text{Na}/\text{vac}-\text{TiS}_3$ ) the situation is similar.

Small changes in the binding energy of  $\text{H}_2$  molecules in comparison with the pristine  $\text{TiS}_3$  can be explained by its electronic structure. According to work of Iyikanat *et al.*<sup>77</sup> removing one S atom from the surface of  $\text{TiS}_3$  does not make any notable effect on the electronic structure of  $\text{TiS}_3$ . The monolayer  $\text{TiS}_3$  conserves its semiconductor character.

Such a lack of increase in adsorption energy of  $\text{H}_2$  when using the decoration with alkali metals ( $\text{Li}$ ,  $\text{Na}$ ) can be explained by the fact that alkali atoms tend to attract  $\text{H}_2$  molecules *via* electrostatic interaction. Such an electrostatic origin of the interaction between  $\text{H}_2$  molecule and alkali cations can be affected by the negatively charged surface of monolayer  $\text{TiS}_3$ ,<sup>77</sup> which on the other hand makes this material interesting in applications such as nanoscale lubricants and charged coatings.





**Table 6** Average adsorption energies ( $E_{\text{ads,H}_2}$ ) (eV) per  $\text{H}_2$  molecule for the first layer of  $\text{H}_2$ -molecule adsorbed on monolayer  $\text{TiS}_3$ , its few defected forms and Li and Na decorated  $\text{TiS}_3$

	$\langle E_{\text{ads,H}_2} \rangle$ (eV)
Pristine $\text{TiS}_3$	0.09
One S vacancy	0.07
Two S vacancies	0.08
Li decorated $\text{TiS}_3$	0.13
Na decorated $\text{TiS}_3$	0.11

## 4. Conclusions

In this paper, first-principles calculations have been carried out to study the possibility of  $\text{H}_2$  molecule to adsorb on the basal plane of monolayer  $\text{TiS}_3$  at various sites. Despite the adsorption energy of pure  $\text{TiS}_3$  at some positions was up to 0.10 eV per  $\text{H}_2$ , the use of traditional methods, such as the decoration of monolayer  $\text{TiS}_3$  with alkali metals (Li/Na), did not have an effect. We believe that this is caused by the negatively charged surfaces of single layer  $\text{TiS}_3$ , influencing the electrostatic component of interaction between alkali metals and hydrogen molecule. The creation of defects, such as sulfur vacancies found ineffective. In addition, the structure and phase stability of monolayer  $\text{TiS}_3$  containing multiple S vacancies was investigated. The structures containing vacancies were found to be stable. It was found that S vacancies do not form clusters, as is the case, for example, of monolayer  $\text{MoS}_2$ .<sup>60</sup> The adsorption of sodium and especially lithium can be used to split the monolayer of  $\text{TiS}_3$  into chains or substantially reduce the width of the  $\text{TiS}_3$  nanobelts and needles. It is also assumed that the adsorption of magnesium can have the same effect as was found in our recent work for the adsorption of magnesium by bulk  $\text{TiS}_3$ .<sup>55</sup>

## Conflicts of interest

There are no conflicts to declare.

## Acknowledgements

This work was supported by the Russian Federation President's scholarship for young scientists and PhD students, project SP-1826.2018.1. The authors thank Petr Tikhonov at ISC RAS for useful discussions. Research was carried out using computational resources provided by Resource Center "Computer Center of SPbU" (<http://cc.spbu.ru>).

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